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Fairchild Semiconductor FMBA06

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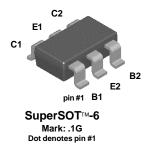
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FMBA06



NPN Multi-Chip General Purpose Amplifier

This device is designed for general purpose amplifier applications at collector currents to 300 mA. Sourced from Process 33.

Absolute Maximum Ratings* $T_A = 25$ °C unless otherwise noted

Symbol	Parameter	Value	Units
V_{CEO}	Collector-Emitter Voltage	80	V
V _{CBO}	Collector-Base Voltage	80	V
V _{EBO}	Emitter-Base Voltage	4.0	V
I _C	Collector Current - Continuous	500	mA
T _J , T _{stg}	Operating and Storage Junction Temperature Range	-55 to +150	°C

^{*}These ratings are limiting values above which the serviceability of any semiconductor device may be impaired.

Thermal Characteristics $T_A = 25$ °C unless otherwise noted

Symbol	Characteristic	Max	Units
		FMBA06	
P _D	Total Device Dissipation	700	mW
	Derate above 25°C	5.6	mW/°C
$R_{\theta JA}$	Thermal Resistance, Junction to Ambient	180	°C/W

¹⁾ These ratings are based on a maximum junction temperature of 150 degrees C.
2) These are steady state limits. The factory should be consulted on applications involving pulsed or low duty cycle operations.

Test Conditions



NPN Multi-Chip General Purpose Amplifier

Min

Тур

Max

(continued)

Units

Electrical Characteristics

Parameter

T_A = 25°C unless otherwise noted

OFF CHA	RACTERISTICS				
$V_{(BR)CEO}$	Collector-Emitter Sustaining Voltage*	$I_C = 1.0 \text{ mA}, I_B = 0$	80		V
V _{(BR)EBO}	Emitter-Base Breakdown Voltage	$I_E = 100 \ \mu A, \ I_C = 0$	4.0		V
I _{CEO}	Collector-Cutoff Current	$V_{CE} = 60 \text{ V}, I_{B} = 0$		0.1	μА
I _{CBO}	Collector-Cutoff Current	$V_{CB} = 80 \text{ V}, I_{E} = 0$		0.1	μΑ

ON CHARACTERISTICS

Symbol

h _{FE}	DC Current Gain	$I_C = 10 \text{ mA}, V_{CE} = 1.0 \text{ V}$ $I_C = 100 \text{ mA}, V_{CE} = 1.0 \text{ V}$	100 100		
V _{CE(sat)}	Collector-Emitter Saturation Voltage	$I_C = 100 \text{ mA}, I_B = 10 \text{ mA}$	100	0.25	V
V _{BE(on)}	Base-Emitter On Voltage	I _C = 100 mA, V _{CE} = 1.0 V		1.2	V

SMALL SIGNAL CHARACTERISTICS

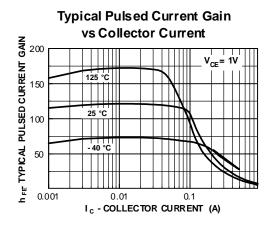
f⊤	Current Gain - Bandwidth Product	$I_C = 10 \text{ mA}, V_{CE} = 2.0 \text{ V},$	10	00	MHz
		f = 100 MHz			

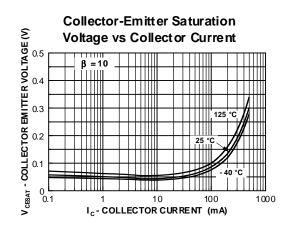
^{*}Pulse Test: Pulse Width ≤ 300 μs, Duty Cycle ≤ 2.0%

Spice Model

 $NPN \ (Is=8.324f \ Xti=3 \ Eg=1.11 \ Vaf=100 \ Bf=12.16K \ Ne=1.368 \ Is==73.27f \ Ikf=.1096 \ Xtb=1.5 \ Br=11.1 \ Nc=2 \ Isc=0 \ Ikr=0 \ Rc=.25 \ Cjc=18.36p \ Mjc=.3843 \ Vjc=.75 \ Fc=.5 \ Cje=55.61p \ Mje=.3834 \ Vje=.75 \ Tr=72.15n \ Tf=516.1p \ Itf=.5 \ Vtf=4 \ Xtf=6 \ Rb=10)$

Typical Characteristics



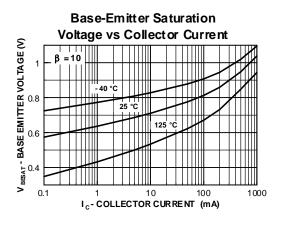


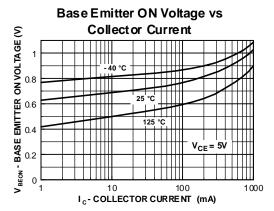


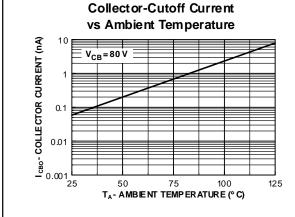
NPN Multi-Chip General Purpose Amplifier

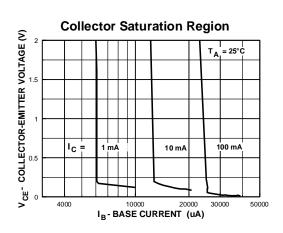
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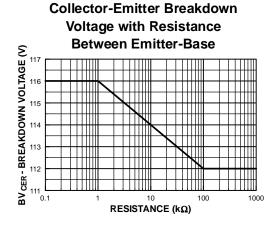
Typical Characteristics (continued)

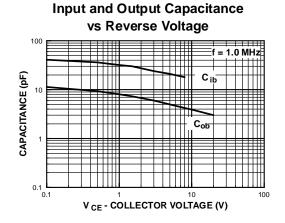










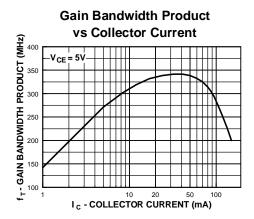


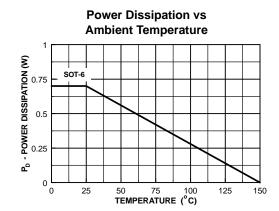


NPN Multi-Chip General Purpose Amplifier

(continued)

Typical Characteristics (continued)







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Datasheet of FMBA06 - TRANS NPN 80V 0.5A SSOT-6

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